# The Kondo e ect and weak localization

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#### I. IN TRODUCTION

The word K ondo means battle in Swahili. This coincidence is fortuitous because in the K ondo e ect, a battle inevitably ensues anytime a magnetic in purity is placed in a nonmagnetic metal. Below some energy scale, the K ondo temperature  $(T_k)$  a lone magnetic in purity is robbed of its spin. Above the K ondo temperature, rapid spin- ip scattering produces a temperature-dependent correction to the resistivity of the form,  $B_k \ln T$ . Until recently, both the K ondo resistivity and  $T_k$  were thought to be determined solely by the host m etal and the magnetic in purity. However, num erous presentations in this volume eattest, there is now overwhelming evidence that both are a ected by the size of the sam  $ple^{1/2r_3^{3/4/5}}$  as well as non-magnetic random scattering<sup>6,7,8,9</sup>. In this paper, I will focus on the theoretical work<sup>10</sup> we have perform ed on the experiments revealing that non-magnetic scattering suppresses the K ondo resistivity in thin K ondo alloys.

In K ondo alloys of the form Cu(Mn), Cu(Fe) and Au(Fe), G iordano and colleagues<sup>6,7,8</sup> observed that introducing non-magnetic impurities suppressed the coe cient of the K ondo logarithm. The Kondo slope, Bk, is a monotonically decreasing function as the mean-free path is decreased. This result is surprising for two reasons. First, disorder gives rise to di usive motion. Hence, relative to a clean sample, conduction electrons spend more time around a given magnetic impurity in the presence of disorder. Naively, this e ect would result in an enhancem ent of the K ondo resistivity. Second, at the time of these experiments, the leading theoretical view was that disorder eliminates the Kondo logarithm and leads to a stronger algebraic divergence of the form  $T^{d=22}$  in the resistivity. Events and K eller<sup>11</sup> were the rst to argue for the emergence of a 1=T in the K ondo self-energy for a d=2 system in the presence of random non-magnetic scattering. A few years lataer, Bohnen and Fisher<sup>12</sup> argued, however, that such a term would not survive in the conductivity. More recently, O hkawa and Fukuyam a<sup>13</sup> and V ladar and Z in any i<sup>14</sup> have developed an extensive diagram matic scheme to re-investigate this problem and also concluded that the algebraic singularity dom inates the K ondo In T. A s a result, these groups conclude that static disorder can mask the K ondo resistivity as T ! 0. The experiments show no singularity of this sort, however. This complete lack of agreement between theory and experiment led us to reevaluate the interplay between disorder and K ondo spin- ip scattering.

A sour work is based heavily on the previous diagram matic expansion of Fukuyam a and

colleagues<sup>13</sup>, it is st in portant to understand how the algebaric divergence en erges from their analysis. W hen non-m agnetic in purities are present, the di usive propagator that describes the resultant m otion

$$D(Q;!) / \frac{1}{(DQ^2 \quad i!)}$$
 (1)

has a di usion pole. Here, Q and ! are the net momentum and energy transfer and D =  $2 h_F$  =dm. W hen such di usive propagators are used to decorate the spin- ip vertices in the K ondo self-energy, the singular dependence found by O hkawa and Fukuyam a<sup>13</sup> obtains as can be seen from the follow ing argum ent. The most divergent contribution to the K ondo self-energy arises from the two-di uson decoration of the K ondo spin- ip vertices. D iagram s of this form involve an integration over the internal momentum line:

$$\frac{1}{\sqrt{2}} \frac{1}{\sqrt{2}} \frac{1}{\sqrt{2}} \frac{\sqrt{2}}{\sqrt{2}} \frac{\sqrt{2}}{\sqrt{2}} \frac{\sqrt{2}}{\sqrt{2}} \frac{\sqrt{2}}{\sqrt{2}} \frac{\sqrt{2}}{\sqrt{2}} \frac{1}{\sqrt{2}} \frac{1}{$$

The absolute value of the frequency appears here because we work in the nite-tem perature M atsubara form alism. The M atsubara frequency ! is proportional to tem perature T. Therefore, the tem perature dependence due to di usons and C ooperons is indeed  $T^{d=22}$ , as can be also veri ed by a more careful calculation<sup>13</sup>, and is a direct consequence of the di uson poles.

The argument leading to the new algebraic dependence is certainly clear. However, it is well-known that spin- ip scattering can cut o the di usion pole. Should this occur then the algebraic dependence will only be valid above a certain temperature, not as T ! 0. Of course, this requires that the feedback e ect of spin- ip scattering on localization physics be included. It is this e ect that has been absent from all previous treatments of the disorder/K ondo problem. Inclusion of the feedback e ect of spin- ip scattering on localization has been the prim ary focus of our work<sup>10</sup>. A key di erence that the feedback e ect introduces is a nontrivial density dependence into the K ondo problem. This di erence arises because di usive propagators which include the spin- ip scattering rate decorate the bare spin- ip vertices in the K ondo self-energy. The spin scattering rate is proportional to the concentration of magnetic in purities. Consequently, a non-zero spin- ip scattering rate arises only if all the magnetic in purities are averaged over. Hence, the feedback e ect represents a departure from the single-im purity physics typically associated with the K ondo problem. That this state of a airs obtains naturally when disorder is present can be seen

from considering the standard weak-localization correction<sup>15</sup>

$$= \frac{e^2}{2^2 h} \ln \frac{1}{2}$$
(3)

to the conductivity in a thin  $\ln , w$  ith the dephasing time o and  $_{o}$  the elastic scattering time. Whenever localization physics is relevant, one has to decide which is the dominant dephasing process. Experiments show that the dephasing time is weakly dependent on temperature<sup>6,7,8</sup>. This is consistent with a dephasing rate that is determined solely by spin- ip scattering. Hence,  $h_{s} / n_{s} hJ^{2} > h_{T}$ , where  $_{T}$  is the dephasing time due to all other processes in the system. Consequently, if spin- ip scattering is the dominant dephasing process, the number of in purities has a lower bound. Our treatment does not include in purity-in purity elects, however. What is crucial here is that the contribution from each in purity must be averaged over to describe the dominant dephasing process. Our central result that is used to compare with the experiments can be derived simply from Eq.(3). In the presence of the K ondo logarithm, the spin- ip scattering rate is given by

$$1 = {}_{s} = 2 = 3^{p} \overline{3} {}_{s}^{\circ} 1 \qquad 4 J_{N} (0) \ln \frac{T_{F}}{T} + \qquad : \qquad (4)$$

Substitution of this result into Eq. (3) and expansion of the logarithm for  $T > T_k$  yields the contribution of spin- ip scattering to the conductivity

$$_{0} \ln \frac{s}{s} = N (0) J_{0} \ln \frac{T_{F}}{T}$$
 (5)

for a d = 2 sample, with  $_0$  the D rude conductivity. Because  $J_0 < 0$ , the K ondo logarithm ic term enhances the spin-scattering time and in turn reduces the magnitude of the weak-localization correction. That is, spin- ip scattering produces an 'antiloclization' e ect. Further, this correction is opposite in sign to the zeroth-order K ondo logarithm. C onsequently, disorder leads to a suppression of the K ondo resistivity. The suppression of the K ondo resistivity follows in mediately from three principles: 1) spin- ip scattering feeds back into the K ondo self-energy to regularize the algebraic divergence, 2) weak localization appears as a negative correction to the conductivity and 3) spin- ip scattering weakens the weak-localization e ect. Hence, the net e ect is a positive correction logarithm ic correction to the conductivity which when added to the negative bare K ondo logarithm leads to a diminished logarithm ic conductivity.

#### II. FORM ULATION OF PROBLEM

The starting point for our analysis is a model H am iltonian  $H = H_0 + H_{sd}$  that contains both norm alim purities

$$H_{o} = \sum_{k}^{X} (\mathbf{"}_{k} \quad \mathbf{"}_{F}) a_{k}^{Y} a_{k} + \frac{v}{k} \sum_{k,k^{0},i}^{X} e^{i(k \ k \ 0) R_{i}} a_{k}^{Y} a_{k^{0}}$$
(6)

as well as m agnetic scatterers

$$H_{sd} = -\frac{J}{R_{n}, k; k^{0}; ;}^{X} e^{i(k k^{0})R_{n}} ; \circ R_{k}^{Y} a_{k^{0}} \circ :$$
(7)

where v m easures the strength of the scattering with the non-m agnetic disorder,  $R_n$  denotes the position of the in purities, m agnetic or otherw ise,  $S_n$  is the spin operator for the m agnetic in purity at site n, and is the volum e. The two natural timescales in this problem are,  ${}_{s}^{\circ}$  and  ${}_{o}$ , the bare m agnetic and non-m agnetic scattering times. In terms of the density of states of the host m etal,  ${}_{o}$  and the concentrations of m agnetic and non-m agnetic scatterers,  $n_s$  and  $n_o$ , respectively, we have that  $h=2{}_{s}^{\circ}=3$   $n_s$   ${}_{o}jJ{}_{J}{}^{2}=4$  and  $h=2{}_{o}=n_{o}$   ${}_{o}jr{}^{2}$ . The total scattering rate is  $1==1={}_{s}^{\circ}+1={}_{o}$ . To measure the strength of the non-m agnetic disorder, we de ne  $=h=(2 \ {}_{F}^{\circ} \ {}_{o})$ . We assume that the concentration of localized spins is dilute so that long-range spin glass elects are irrelevant. A lso, we work in the regime in which normal in purity scattering dom inates,  $1={}_{o}=1={}_{s}^{\circ}$ .

D escribing scattering in the presence of a weakly disordered potential requires C coperon and di uson propagators. The traditional form of such propagators, C (Q;!) = D (Q;!) /  $(D Q^2 \quad i!)^1$ , was used extensively in the early treatments<sup>13</sup> of the disordered K ondo problem. However, as remarked in the introduction, such a procedure assumes that di usive motion with a di usion pole remains intact even in the presence of oscillating elds created by spin- ip scattering. It is this assumption that leads to the divergence found earlier by Fukuyam a and co-workers<sup>13</sup>. To alleviate this problem, we include the all-in portant feedback e ect spin- ip scattering has on such di usive processes. If all scattering processes are treated in the rst Born approximation, the D yson-like integral equation,

$$D = + \overline{U U}^{X} G^{R} G^{A} D$$
 (8)

describes all ladder diagram s with the spin-dependent potential

The G reek letters denote the spin indices on the upper and lower electron lines in the di uson ladder and repeated indices are sum m ed over. The advanced and retarded G reen functions are given by  $G^{A}^{1} = {}_{F} p^{2} = 2m$  i=2 + h and  $G^{R}^{1} = {}_{F} + !$   $p^{2}_{f} = 2m + i = 2 + h$  respectively. Noting that

$${}^{X} G^{R} G^{A} = {}^{X} \frac{G^{R} G^{A}}{(G^{R})^{1} (G^{A})^{1}}$$
(10)

we arrive at the solution for the di uson,

$$D = \frac{h}{4 (DQ^{2} i!)} (+) + \frac{h}{4 (DQ^{2} i! + 4=3^{0}_{s})} (3) (11)$$

The analogous integral equation for the Cooperon

$$C = + \overline{U \ U}^{X} G^{R} G^{A} C$$
(12)

can be solved analogously to yield,

$$C = \frac{h}{4 (DQ^{2} \quad i! + 2= \frac{0}{s})} ( )$$
  
+  $\frac{h}{4 (DQ^{2} \quad i! + 2=3\frac{0}{s})} (3 + ): (13)$ 

where and are spin indices. The dot-product  $= x + y + z + z^{-2}$ .

### III. SELF ENERGY

As is evident, even in the presence of spin- ip scattering, the di uson still retains its di uson pole in the S = 0 channel. Hence, we will be back to where we started if the S = 0 di uson still contributes to the self-energy. We now show that this contribution vanishes identically to all orders of perturbation theory. Consider the self-energy diagram s shown in Fig.(1).

To illustrate how the self-energy diagram s in Fig. 1 are evaluated let's focus on the st two diagram s with the di uson vertex decorations. The sum of the two self-energy diagram s is

$$D_{3q}(k;i_{n}) = n_{s}J^{3}T \qquad (n(n+!))V \qquad (i!,i!_{m})$$

$$U_{1}(i_{n}+i!_{m};Q)G \qquad (i_{n}+i!_{n};k+Q)$$

$$D \qquad (i!,Q)D \qquad (i!,Q) \qquad (14)$$

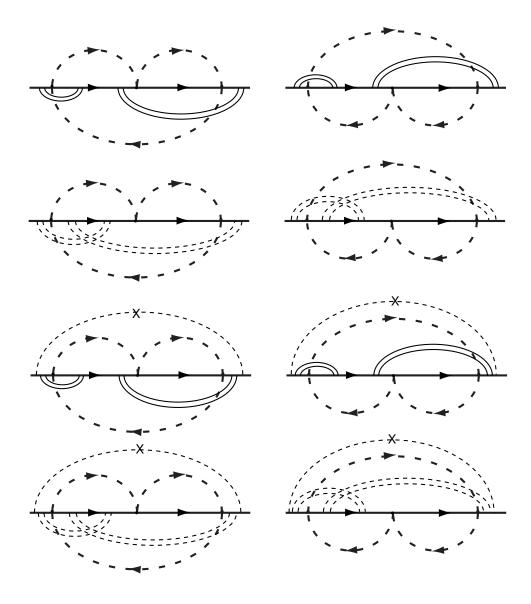


FIG.1: Feynm an diagram s contributing to the K ondo self-energy. The dashed lines correspond to A brikosov pseudoferm ions and the double solid lines to di usons and double dashed lines to the C ooperons. The G reek letters indicate the spin. The X indicates a single non-m agnetic in purity scattering event. Such diagram s are known as the rainbow diagram s.

where G (i;q) is the electron G reen function

$$G(i;q) = \frac{1}{i + F} + \frac{hq^2 = 2m + i(h=2) \operatorname{sign}(f)}{i + F};$$
(15)

and the electron energies are given by the M atsubara frequencies,  $_n = (2n + 1) T$ . The pseudoferm ion energies are de ned in terms of  $z_k = (2k + 1) T$  and  $! \cdot = 21 T$ . The range of sum m ation over the momentum Q and energy  $! \cdot transfers$  is limited by the range

of validity of the di usion approximation,  $D Q^2 < h = and ! < h =$ . The step function

(x) appears in the expression because the di usion propagators are only non-zero if the impurity ladders connect electrons on di erent sides of the Ferm i surface. The sum mation over momenta  $k^0$  and  $k^{00}$  in the Green functions adjacent to the spin vertices is already included in the de nition of the di uson. The Green functions in Eq. (14) can be simplied using

$$\begin{array}{l} X \\ G (i_{n} + i!_{m};q) \\ G (i_{n} + i!_{n};k+Q) \\ \end{array} \begin{array}{l} i_{0} ("_{F}) \operatorname{sign}(_{n} + !_{m}); \\ \frac{2}{i_{h}} \operatorname{sign}(_{n} + !_{n}) = i\frac{2}{h} \operatorname{sign}(_{n}): \end{array}$$
(16)

The set approximation can be obtained by integration around the Fermi surface. The second approximation makes use of the fact that the momentum k and energy  $_n$  are close to the Fermi surface (within the energy shell of width T), and the momentum and energy transfers allowed by the di usion propagator are less than h= .

The pseudoferm ion part,

$$V \quad (!,;!_{m}) = \frac{1}{16} \frac{m 0}{i! } (1 \quad v_{0}) + \frac{v_{0}}{i!_{m}} (1 \quad m 0) \quad \frac{v_{m}}{i! } (1 \quad v_{0}) \quad () \quad (17)$$

involves a trace over the impurity spin states. The internal spin indices are not summed over because the electron spin can be ipped by the di usons. A fler substituting all the ingredients into Eq. (14) and perform ing the summation over the spin indices, the self-energy becomes

Rem arkably, the divergent S = 0 part of the di uson drops out, and as a result the singular tem perature dependence in the resistivity disappears.

But what is the source of this cancellation and is it exact? By careful exam ination of the pseudoferm ion contribution Eq. (17), we see that the sum over the spin indices in the self-energy Eq. (14)] separates into two identical sums of the form, P D a. If we use the identity P ( ) a = a, we not immediately that the cancellation of the S = 0 di uson

from the  $3^{rd}$  order K ondo self-energy is exact. To any order in J in the most divergent approximation, the cancellation of the S = 0 di uson can be seen as follows. Within this scheme, each di uson encircles a vertex that is exactly equal to the Abrikosov<sup>16</sup> vertex function =  $J_e$  S, with J de ned within the parquet summation. When this function is now multiplied by D <sup>S=0</sup> and summed over the spin indices, the cancellation to all orders follows in mediately from Eq. (18). Note that this cancellation relies on the spin algebra and hence is not tied to the approximations used to obtain D <sup>S=0</sup>. Consequently, the cancellation of the S = 0 component of the di uson is fundamentally tied to the fact that the K ondo interaction does not conserve the electron's spin. This cancellation theorem which signi es that the K ondo logarithm remains in tact is in the spirit of Anderson's theorem that non-m agnetic in purities do not a ect  $T_c$  for s-wave superconductors. Recently, Chakravarty and N ayak<sup>17</sup> have shown that in the very weak-disorder lim it, a true Anderson theorem exists in which disorder does scale out of the K ondo problem.

As advertised, the cancellation of the di usion pole suppresses the algebraic divergence of the self-energy. To see how this emerges, we continue with our analysis of the set two diagrams in Fig.(1). We lim it ourselves to 2D case, and hence

where is the dimensionless disorder de ned earlier. From this self energy, we de ne the scattering rate as follows:

$$\frac{h}{2 \frac{q}{D}} = \frac{Z}{\frac{q}{D}} \cdot \frac{(f)}{\frac{q}{D}} \cdot (Im \frac{D}{3q}(k; + i0))d$$
$$= \frac{Z}{f(1)} \cdot \frac{(f)(m - 3qD}{\frac{q}{D}(k; + i0))}{\frac{q}{Q}}d:$$

C learly, one cannot evaluate this expression just by setting = 0 because of the singular temperature dependence in the self-energy. We will compute this expression by contour integration in the complex -plane. The self-energy has two poles in the upper half-plane. Hence if we close the contour in the lower half-plane, then the integral will be equal to the sum of the residues in the points where the Ferm infunction f() has poles,  $_{k} = i(2k+1)$  T:

$$\frac{h}{2 \frac{q}{D}} = 2 \text{ if } \frac{X}{k} \frac{\text{@Im} 3qD}{\text{@}} \text{(k; + i0)}}{\text{@}} = \frac{1}{2}$$

$$=\frac{x^{\frac{1}{2}}}{x_{m=0}}\frac{1}{(m+k+1)(m+k+1+1)} \frac{1}{(m+k+1)} + \frac{1}{(m+k+1+1)} + \frac{1}{(m+k+1+1)}$$

where A is the coe cient of the self-energy and  $= 2 h=3 T_s^0$ . In the double sum over m and k there are (m + k + 1) N identical elements. Therefore, the sum can be transformed to a sum over N times N. Now if we use the series expansion for the digam ma, (x) =d ln (x)=dx, and trigam ma,  ${}^0(x) = d^2 \ln (x)=dx^2$  functions,

$$(1 + x) = + z \frac{x^{2}}{N} \frac{1}{N(N + x)}$$
$$^{0}(1 + x) = \frac{x^{2}}{N + 1} \frac{1}{(N + x)^{2}};$$

and de nea new function

F (x) 
$$\frac{(1 + x) +}{x} + {}^{0}(1 + x)$$

then the result for the contribution to the scattering rate becom es

$$\frac{h}{2 \frac{q}{D}} = \frac{3}{2} n_{s} {}^{2}_{0} J^{3} \frac{h}{T} F \frac{2 h}{3 T {}^{0}_{s}} :$$
(19)

For smallargum ent, x 1, F (x) (2) =  ${}^{2}$ =6; for large argum ent x 1, F (x) h(x)=x. Hence we conclude that there are two regimes, corresponding to \high" ( $h={}^{0}_{s} > T$ ) and \low" ( $h={}^{0}_{s} < T$ ) in purity concentrations, in which the di uson corrections behave logarithm ically in temperature and as 1=T, respectively. In other words, the 1=T behavior is cut-o at the temperatures below  $h={}^{0}_{s}$ . Now let us consider the rest of the diagram s, namely the diagram s that involve C ooperon propagators, and the diagram s with the external single in purity line.

$$D_{3q}(k;i_{n}) = n_{s}J^{3}T \qquad (n(n + ! \cdot))V \qquad (i! \cdot;i!_{m})$$

$$= G(i_{n} + i!_{m};q)G(i_{n} + i! \cdot;k + Q)$$

$$= C \qquad (i! \cdot;Q)C \qquad (i! \cdot;Q): \qquad (20)$$

The only di erence compared to the di uson self-energy contribution is the di erent spin indexing of the C opperons compared to the di usons. This is because the C opperon propagators need to be \crossed" in order to have the sam e m om entum transfers without phase space restrictions. Sum m ing over the spin indices reduces the problem to one in which the product of the C opperons is spin independent and equal to:

$$C^{2} = \frac{h^{2}}{2^{2}} \frac{1}{(DQ^{2} \quad i! + 2= \frac{0}{s})^{2}} + \frac{1}{(DQ^{2} \quad i! + 2=3\frac{0}{s})^{2}}$$
(21)

Now we can continue in exactly the same way as in the di uson case to obtain for the scattering rate correction

$$\frac{h}{2 c} = \frac{3}{2} n_{s} {}^{2}_{0} J^{3} \frac{h}{T} \frac{1}{2} F \frac{h}{T s} + \frac{1}{2} F \frac{h}{3 T s} = \frac{1}{2} F \frac{h}{3 T s}$$
(22)

At high tem peratures,  $T > h = {}^{0}_{s}$  we again recover the 1=T behavior, and for low tem peratures,  $T < h = {}^{0}_{s}$ , the logarithm ic behavior obtains.

Finally, we need to consider the set of diagram s that contain one external in purity line (the rainbow diagram s). We will prove now that such diagram s are equal to the corresponding diagram s without the in purity line times the factor of (-1/2). Unlike the diagram s that we considered before, the internal G reen function G ( $i_n + i! \cdot k + Q$ ) can no longer be replaced by its value at the Ferm i surface, 2i = h. Instead, a sum over the interne ediate m om entum of a product of three G reen functions needs to be computed:

$$\frac{jy^{2}}{jx^{2}_{1}} \frac{1}{(i_{n} + F_{k^{0}} + ih=2)^{2}(i_{n} + i! + F_{k^{0}+2} - ih=2)}$$

$$\frac{jy^{2}_{1}}{jx^{2}_{1}} \frac{0d(x)}{(x + ih=2)^{2}(x - ih=2)} = 2 i_{0}jy^{2}\frac{1}{(2ih=2)^{2}} = i = h;$$

$$(23)$$

In deriving this relation, we set Q and !. to zero, since they are small. Therefore the sum of the diagram s with and without the external in purity lines is two times smaller that sum of the di uson and Cooperon diagram s that we derived before. However, there is a factor of 2 that comes from two possible internal electron lines to which the di usion propagators can be attached. As a result, the sum of all diagram s happens to be exactly equal to the sum of two contributions that we already computed. Hence the total quantum correction to the scattering time due to the K ondo diagram s in Fig. 1 is

$$\frac{1}{q} = \frac{1}{\frac{q}{D}} + \frac{1}{\frac{q}{C}};$$

with  $1 = \frac{q}{D}$  and  $1 = \frac{q}{C}$  given by Eq. (19) and Eq. (22), respectively.

## IV. CONDUCTIVITY

The total conductivity is a sum of the D rude contribution with the transport scattering time, and the weak localization correction. The transport scattering rate is composed of elastic scattering, the second order in J spin scattering, the third order in J (K ondo) scattering and the quantum corrections com puted above.

$$\frac{1}{tr} = \frac{1}{0} + \frac{1}{0} + \frac{1}{K} + \frac{1}{q} + \frac{1}{q} + \frac{1}{q}$$
(24)

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Of these contributions, only the last three have non-trivial tem perature dependence. The total conductivity is

$$(T) = \frac{e^2 n_{tr}}{m} + {}_{WL} = {}_{0} 1 \frac{}{K} \frac{}{s} \frac{}{D} \frac{}{C} + \frac{}{0} \frac{}{K} \frac{}{s} \frac{}{s} \frac{}{c}$$
(25)

where  $_0$  is the tem perature-independent part of the conductivity. There are also more complex conductivity diagram s that involve both the spin-dependent pseudoferm ion part and the di usion propagators, but they can be shown to cancel out<sup>13</sup>.

The derived expressions for  $_{D}^{q}$  and  $_{C}^{q}$  have simple asymptotic behavior. For d = 2 in the lim it T  $h = _{S}^{0}$ , we recover the inverse temperature dependence

$$\frac{h}{2^{C}} = \frac{h}{2^{D}} - \frac{h_{0} J}{3} \frac{h}{{}_{S}^{0}T} - {}_{0} J \frac{h}{2^{C}}$$
(26)

of Refs. (<sup>13,14</sup>). W ithout the di usion pole cancellation, the lower bound in temperature for the 1=T behavior would be set by max [h= ;T<sub>K</sub>], where is the inelastic scattering time. We nd here that by explicitly including spin-scattering in the di usion propagators, the algebraic behavior occurs when  $h=(_{s}^{0}T)$  1. We will see later that as a result of this restriction, the contribution of the 1=T term to the conductivity is negligible. In the opposite regime, T  $h=_{s}^{0}$ , the scattering rates

$$\frac{h}{2^{D}} = \frac{3}{2} \,_{0} \,_{J} - \frac{h}{\ln} \frac{h}{T_{s}^{0}}$$

$$\frac{h}{2^{C}} = 2_{0} \,_{J} - \frac{h}{\ln} \frac{h}{T_{s}^{0}}$$
(27)

are both logarithm ic functions of tem perature.

The weak-localization contribution is given in Eq.(5. We collect all the contributions discussed above to determ ine the tem perature-dependent conductivity. In the tem perature range  $T_K < T < h = {}_{s}^{0}$ , Cooperon, di uson, and weak-localization corrections are all logarithm ic in tem perature. Combining the results from Eq. (27) with the weak-localization correction, we nd that the magnitude of the logarithm ic part of the conductivity

$${}^{\mathrm{T}} = {}_{0} \frac{4 {}_{0} J}{{}_{\mathrm{s}}^{0}} 1 + 0.75 - \frac{{}_{\mathrm{s}}^{0}}{{}_{\mathrm{s}}^{\mathrm{F}}} \ln \frac{{}_{\mathrm{T}}}{{}_{\mathrm{T}}^{\mathrm{F}}} :$$
(28)

The rst term in this expression arises from the unperturbed K ondo e ect and the latter from the interplay with disorder. Inclusion of disorder in the self-energy, even after inclusion of the negative W L correction, enhances the K ondo resistivity relative to a clean system result.

For tem peratures  $T = h_s^0$ , the self-energy contribution to the relaxation time scales as 1=T, whereas the weak-localization correction is proportional to  $\ln T$ . However, comparison of the magnitude of these corrections reveals that the weak-localization term dom in terms, and the magnitude of the resultant tem perature-dependent conductivity

$${}^{\rm r} = {}_{0} \frac{4 {}_{0} {}_{0} {}_{\rm S}}{}_{\rm s} 1 {}_{-} \frac{{}_{\rm s}^{0}}{}_{-} \ln \frac{{}^{\rm r}_{\rm F}}{{}_{\rm T}}$$
(29)

is suppressed by the disorder. Let us now apply our results to thin  $\ln s$  with a thickness, L. We are interested in thin  $\ln s$ , such that < L = L. Because < L, the electron gas is characterized by a 3-dimensional density of states  $_0 = 1 = (2 \ )^2 \ (2m = lf)^{3=2} \ _F^{1=2}$  and di usion constant given by  $D = 2 h_F = 3m$ . Since the dephasing length L exceeds the  $\ln$  thickness, such a  $\ln$  should be treated as quasi-2D with respect to weak localization. That means that the momentum -transfer sum mation in the di usion propagators must be restricted to the plane, or  $P_Q$  !  $(1=L)^P_Q_{(2D)}$ . The density of states that arises from converting this sum into an integral is the two-dimensional density of states,  $2D_Q = 0 = k_F$ . Hence, the self-energy diagram s with the di usion propagators will generate a size-dependence to the conductivity of the form  $1=(k_F L)$ . The explicit nite-size weak-localization correction is  $l^3$ .

$$_{\rm W \ L} = \frac{e^2}{2^2 \, h L} \ln \frac{3^{\rm p} \, \overline{3}_{\rm s}}{2} \sinh \frac{L}{L} \frac{1}{L}$$

. The size-dependence under the logarithm yields an e ective size dependence in the spinrelaxation time. This size dependence should be observable in the standard W L magnetoresistance measurements in the weak magnetic elds. However, it will not a ect the temperature dependence of the conductivity. The only size dependence that is coupled to the temperature is the 1=L prefactor of the weak-localization correction.

We now combine these results in the low and high-temperature limits discussed earlier. In the two limits, we obtain conductivities

$${}^{T} = \begin{cases} \circ & 0 \frac{4 \quad 0 J}{S} \quad 1 + \frac{0.25h \ s}{m \ k_{\rm F} \ L^{\ 2}} \quad \ln \frac{F}{T} \quad \text{if} \quad T_{\rm K} \quad T < h = {}^{0}_{\rm S} \\ \Rightarrow & 0 \frac{4 \quad J}{S} \quad 1 \quad \frac{1.5h \ s}{m \ k_{\rm F} \ L^{\ 2}} \quad \ln \frac{F}{T} \quad \text{if} \quad T_{\rm K} ; h = {}^{0}_{\rm S} \quad T \end{cases}$$
(30)

that have an explicit size and disorder correction that scales as  $1=(^{2}L)$ . The fact that only the coe cient of  $\ln T$ , but not the form of the tem perature dependence, is modiled is

a direct consequence of the di usion pole cancellation theorem . W hen magnetic impurity density is high, we nd and enhancement of the K ondo logarithm. This is an intuitive result since, qualitatively, di usive motion of electrons is expected to enhance the probability of repeated scattering that generates the K ondo e ect. The surprising nding is that in the other regime, an overall suppression of the logarithm ic correction in the conductivity is obtained. W hile the self-energy enhancement is always present, as it can be seen from the positive self-energy corrections to the transport scattering rate [Eqs. (19) and (22)], this e ect is completely overwhelmed in the conductivity by the W L correction which also acquires ln T dependence due to the K ondo contribution to the dephasing rate.

### V. EXPERIMENTAL APPLICATIONS

In the experiments of B lachly and G iordano<sup>6</sup>, the impurity concentration was such that,  $h = {}^{0}_{s}$  0:1 K, which is much less than the K ondo temperature for Cu (Fe), T<sub>K</sub> 3 K. Therefore, the second of Eqs. (30) should apply. Figure 2 shows a comparison between the experimental data of B lachly and G iordano<sup>6</sup> and the theoretical predictions. Each black square corresponds to one sample. The best t to the data was obtained with  ${}^{0}_{s} =$ 1:3 10<sup>10</sup> s, whereas experimentally the spin scattering time is on the order of 10 10<sup>11</sup>. This discrepancy also persists for the Cu (M n) alloys for thicknesses of order 750 400A. However, for the thinnest Cu (M n) alloys<sup>8</sup> Jacobs and G iordano have shown that excellent agreement exists between theory and experiment for  ${}^{\circ}_{s} = 6$  10<sup>11</sup>, which is well within the experimental uncertainty of the measured value,  ${}^{\circ}_{s} = 6$  10<sup>11</sup>.

W hile theory and experiment are in good agreement for thin samples, there is a key experimental ambiguity that surrounds these results, namely is there a well-de ned K ondo temperature for the thinnest samples and for those with mean free paths of order 250A. This question is most relevant in light of the experiments of Yanson and colleagues<sup>9</sup> who have shown that in point contacts, huge uctuations in the K ondo temperature occur for contact diameters of order 100A. For an inhom ogeneous system, the density of states becomes position dependent:  $_0(x) = _0 + _0(x)$ . Consequently, the position-dependent K ondo temperature will be

 $T_{K}(x) = "_{F} \exp[1=2_{0}(x)J] \qquad "_{F} \exp[1=2_{0}(x)J] = T_{K} \exp[-_{0}(x)=2_{0}^{2}J]:$ (31)

Typically  $_0J$  0:1, which means that even a 10% change in the density of states can produce 100% change in the K ondo tem perature. The e ect is even stronger for alloys with lower K ondo tem peratures. From elementary scattering theory,  $_0(x) = _01 = \frac{p}{k_F}$ , where

is the smaller of the mean-free path and the sample thickness. For = 100 A,  $_0(x) = _0 = 1$ . Hence, we expect a 100% change in the K ondo temperature for such samples. Those in purities having high K ondo temperatures will not contribute to the K ondo resistivity. C onsequently, uctuations in the density of states can electively decrease the concentration of active spin- ip scattering centers that could contribute to the K ondo logarithm. This will lead to an enhancement in the spin-scattering rate over the bulk value. Hence, the question as to how well-de ned the K ondo temperature is in the thinnest and most disordered samples should be resolved before a complete experimental understanding of the K ondo elect in dirty alloys can be reached.

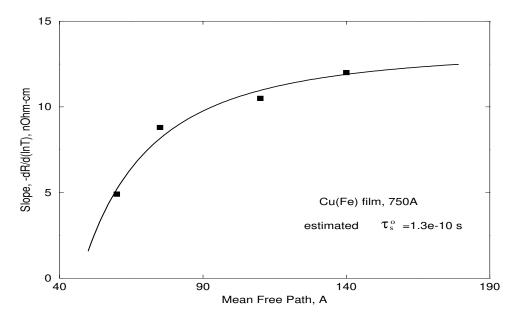


FIG. 2: C om parison of the theoretical K ondo resistivity predicted from the second of Eqs. (30) with the experimental data of B lachly and G iordano. The horizontal axis measures the strength of the static disorder through the mean-free path.

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